UNITED STATES SECURITIES AND EXCHANGE COMMISSION

Washington, D.C. 20549

FORM 8-K

CURRENT REPORT Pursuant to Section 13 or 15(d) of the Securities Exchange Act of 1934

March 23, 2011

Date of Report (Date of earliest event reported)

DIODES INCORPORATED

(Exact name of registrant as specified in its charter)

002-25577

95-2039518

Delaware

(State or other	(Commission File Number)	(I.R.S. Employer			
jurisdiction of		Identification No.)			
incorporation)					
15660 Dallas Parkway, Suite	850				
Dallas, Texas		75248			
(Address of principal executive of	fices)	(Zip Code)			
	(972) 385-2810				
	(Registrant's telephone number, including area code)				
eck the appropriate box below if the Form 8-K fil ovisions:	ing is intended to simultaneously satisfy the filing obligation	on of the registrant under any of the following			
☐ Written communications pursuant to Rule 425 under the Securities Act (17 CFR 230.425)					
Soliciting material pursuant to Rule 14a-12 unde	er the Exchange Act (17 CFR 240.14a-12)				
Pre-commencement communications pursuant to Rule 14d-2(b) under the Exchange Act (17 CFR 240.14d-2(b))					
Pre-commencement communications pursuant to	Rule 13e-4(c) under the Exchange Act (17 CFR 240.13e-4((c))			

Item 7.01. Regulation FD Disclosure.

On March 23, 2011, the Company representative attended Sidoti 15th Annual Emerging Growth Institutional Investor Forum and held a presentation meeting. A copy of the presentation slides is attached as <u>Exhibit 99.1</u> to this Report.

The information in this Item 7.01, including Exhibit 99.1, will not be treated as filed for the purposes of Section 18 of the Securities Exchange Act of 1934 (the "Exchange Act") or otherwise subject to the liabilities of that section. This information will not be incorporated by reference into a filing under the Securities Act of 1933, or into another filing under the Exchange Act, unless that filing expressly refers to specific information in this Report. The furnishing of the information in this Item 7.01 is not intended to, and does not, constitute a representation that such furnishing is required by Regulation FD or that the information in this Item 7.01 is material information that is not otherwise publicly available.

In the presentation, the Company utilized financial measures and terms not calculated in accordance with generally accepted accounting principles in the United States ("GAAP") in order to provide stockholders with an alternative method for assessing our operating results in a manner that enables stockholders to more thoroughly evaluate our current performance as compared to past performance. We also believe these non-GAAP measures provide stockholders with a more informed baseline for modeling the Company's future financial performance. Our management uses these non-GAAP measures for the same purpose. We believe that our stockholders should have access to, and that we are obligated to provide, the same set of tools that we use in analyzing our results. These non-GAAP measures should be considered in addition to results prepared in accordance with GAAP, but should not be considered a substitute for or superior to GAAP results. See Exhibit 99.1 to the Company's Form 8-K, filed on February 15, 2011 for definitions of the non-GAAP financial measures, together with an explanation of why management uses these measures and why management believes that these non-GAAP financial measures are useful to stockholders. In addition, in Exhibit 99.1 to the Company's Form 8-K, filed on February 15, 2011, we have provided tables to reconcile the non-GAAP financial measures utilized to GAAP financial measures.

Cautionary Information Regarding Forward-Looking Statements

Except for the historical and factual information contained in the accompanying slides attached as exhibits to this Report, the matters set forth therein are forward-looking statements within the meaning of the "safe harbor" provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements are subject to risks and uncertainties that may cause actual results to differ materially, including, but are not limited to, such factors as Diodes' business and growth strategy; the introduction and market reception to new product announcements; fluctuations in product demand and supply; prospects of the global economy; continued introduction of new products; Diodes' ability to maintain customer and vendor relationships; technological advancements; impact of competitive products and pricing; growth in targeted markets; successful integration of acquired companies and/or assets; Diodes' ability to successfully make additional acquisitions; risks of domestic and foreign operations, including excessive operation costs, labor shortages and Diodes' joint venture prospects; unfavorable currency exchange rates; availability of tax credits; Diodes' ability to maintain its current growth strategy or continue to maintain its current performance, costs and loadings in manufacturing facilities; the global economic weakness may be more severe or last longer than Diodes currently anticipate; and other information detailed from time to time in Diodes' filings with the United States Securities and Exchange Commission. You should not place undue reliance on these forward-looking statements, which speak only as of the date of the presentation slides. The Company undertakes no obligation to update publicly any forward-looking statements, whether as a result of new information, future events or otherwise.

Item 9.01. Financial Statements and Exhibits.

(d) Exhibits

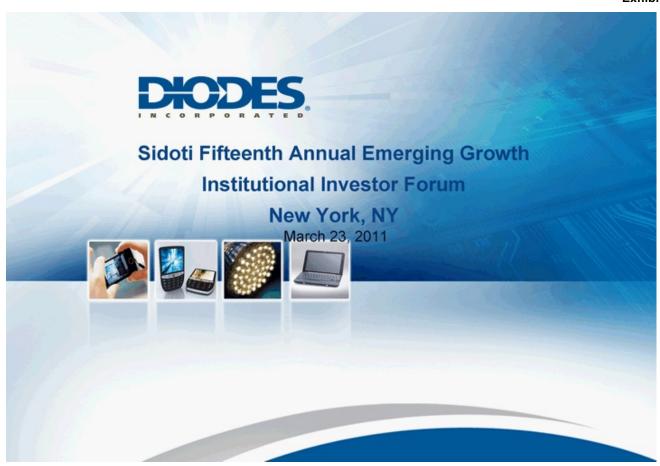
Exhibit	
Number	Description
99.1	Presentation Slides for Sidoti 15th Annual Emerging Growth Institutional Investor Forum in New York, New York on March 23, 2011

SIGNATURES

Pursuant to the requirements of the Securities Exchange Act of 1934, the Registrant has duly caused this report to be signed on its behalf by the undersigned hereunto duly authorized.

Dated: March 23, 2011 DIODES INCORPORATED

By /s/ Richard D. White RICHARD D. WHITE Chief Financial Officer



Safe Harbor Statement

Any statements set forth herein that are not historical facts are forward-looking statements that involve risks and uncertainties that could cause actual results to differ materially from those in the forward-looking statements. Such forward-looking statements include, but are not limited to, statements regarding Diodes' first quarter of 2011 business outlook, including revenue is expected to be flat to down five percentage points compared to fourth quarter 2010; gross margin is expected to be 36.5 percent, plus or minus one percentage point; operating expenses are anticipated to be comparable to fourth quarter levels on a percent of revenue basis; income tax rate is expected to range between 17 and 23 percent; and shares used to calculate GAAP EPS for the first quarter are anticipated to be approximately 46.3 million.

Potential risks and uncertainties include, but are not limited to, such factors as Diodes' business and growth strategy; the introduction and market reception to new product announcements; fluctuations in product demand and supply; prospects of the global economy; continued introduction of new products; Diodes' ability to maintain customer and vendor relationships; technological advancements; impact of competitive products and pricing; growth in targeted markets; successful integration of acquired companies and/or assets; Diodes' ability to successfully make additional acquisitions; risks of domestic and foreign operations, including excessive operation costs, labor shortages and Diodes' joint venture prospects; unfavorable currency exchange rates; availability of tax credits; Diodes' ability to maintain its current growth strategy or continue to maintain its current performance, costs and loadings in manufacturing facilities; the global economic weakness may be more severe or last longer than Diodes currently anticipate; and other information detailed from time to time in filings with the United States Securities and Exchange Commission.

This presentation also contains non-GAAP measures. See the Company's press release on February 9, 2011 titled "Diodes Incorporated Reports Fiscal 2010 and Fourth Quarter Financial Results" for detailed information related to the Company's non-GAAP measures and a reconciliation of GAAP net income (loss) to non-GAAP net income (loss).



Management Representative



Dr. Keh-Shew Lu President and CEO

President and CEO Since 2005
Director – Diodes 9 years
Texas Instruments 27 years

Experience:

- Senior Vice President of TI Worldwide Analog and Logic
- · Senior Vice President of TI Worldwide Memory
- · President of Texas Instruments Asia

Education:

- Master's Degree and Doctorate in Electrical Engineering Texas Tech University
- Bachelor's Degree in Engineering National Cheng Kung University - Taiwan



Company Representative

Laura Mehrl

Director of Investor Relations

Since May 2010

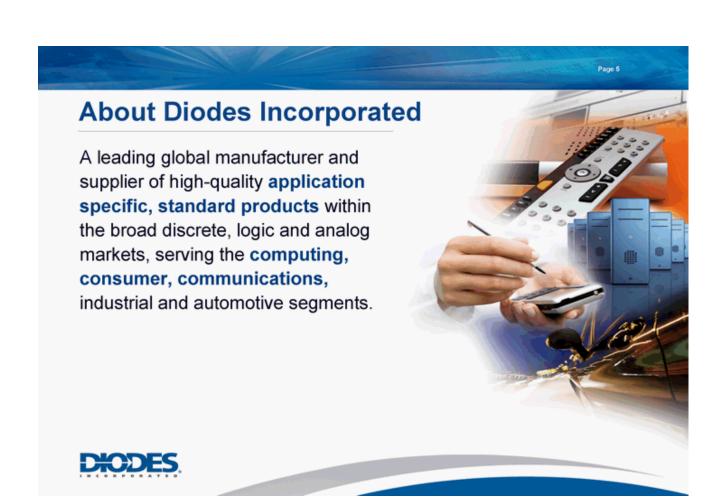
Experience:

- Director of Investor Relations, Diodes Incorporated, Dallas, Texas
- Senior Business Development Manager, STMicroelectronics, Carrollton, Texas
- Sales Director for Analog Devices Inc., Shanghai, China
- Product Marketing Manager at Texas Instruments (TI), Dallas, Texas
- Senior Engineer at Lattice Semiconductor Inc., Hillsboro, Oregon
- Wafer fab design engineer and product engineer at TI, Lubbock, Texas

Education:

- · MBA with concentration in International Marketing, Texas Tech University
- · BS in Electrical and Computer Engineering, University of Iowa





Business Objective

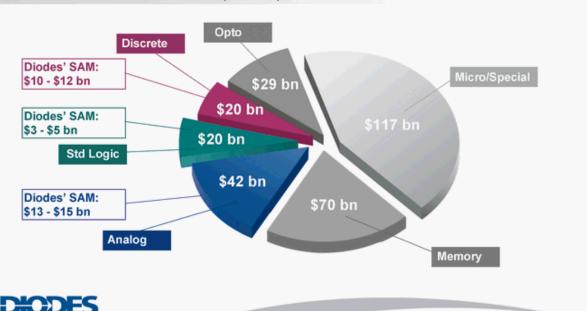
To consistently achieve above-market profitable growth, utilizing our innovative and cost-effective packaging technology, suited for high volume, high growth markets by leveraging process expertise and design excellence to deliver high quality semiconductor products





Significant Market Opportunity

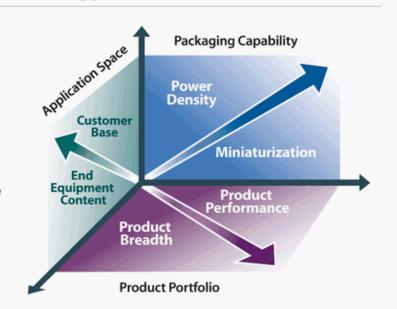




Diodes Growth Strategy

Many Paths for Growth:

- Product portfolio
 - Product arena
 - Product line expansion
 - Performance enhancement
- Application space
 - Targeted end equipments
 - Broad customer base
 - Increased product coverage
- Packaging breadth
 - Broad packaging portfolio
 - Increased power density
 - Small form factor





Product Portfolio Progression

2006

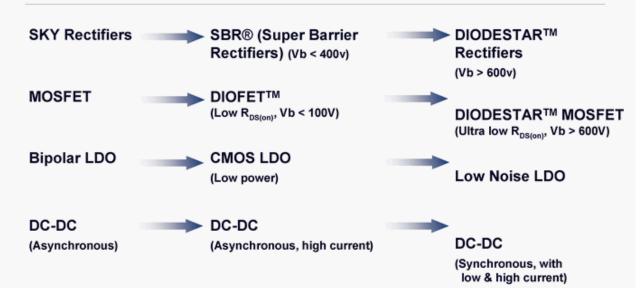
- Discrete
 - Diodes
 - MOSFET
 - Rectifiers
 - Transistor
 - Protection Devices
- Analog
 - Power Management
 - Power Switches
 - Standard Linear
 - Sensors
 - LED Drivers
- Logic
 - Low Voltage CMOS
 - High Speed CMOS
 - Advanced Ultra-Low Power CMOS



2010



Performance Enhancement



Diodes' product upgrade has expanded our SAM



Efficiency, Functionality, and Control for Smart Phones

LCD Backlighting

LED Drivers Boost Converters Schottky Diodes

LED Flash Module

Camera Flash Drivers ZXMN series MOSFETs

LCD / OLED Display Bias

LCD Bias ICs OLED Bias ICs Schottky Diodes

Battery Power Management

USB Power Switches Current Monitors Charger ICs Low-Saturation Bipolar Transistors ZXMP series MOSFETs



RF Power Amplifier

Low Dropout Regulators

System Voltage Conversion

Low Dropout Regulators DC-DC Converters Schottky Diodes Low-Saturation Bipolar Transistors

• Flip / Slide Detection

Hall Effect Sensors Hall Effect Drivers

Keypad Backlighting

LED Drivers **Boost Converters** Schottky Diodes



Strong Relationships Drive LCD/LED TV Product Roadmaps

LCD Display Buffer

40V High-gain BJT

System Power Conversion

Low Dropout Regulators
DC-DC Converters
Voltage References
Synchronous MOSFET Controllers
40V/100V SBR and Schottkys
Bridge Rectifier Diodes

LCD LED Backlighting

Current Monitors 400V High-gain NPN BJT 60V/100V High-gain NPN BJT 60V/100V N-channel MOSFETS

CCFL Backlighting

30V Low On-resistance MOSFETs

Antenna Tuner

DC-DC Converters 40V Schottkys

System Interface

USB Power Switches Zener and TVS Arrays

System Power Management

Buck DC-DC Converters
Low Dropout Regulators
20V/30V/40V SBR® and Schottkys
30V P-Channel MOSFETs
30V Low-saturation PNP BJT

Audio Amplifier

Buck DC-DC Converters Schottky Diodes SBR



Product Breadth and Performance for Computing Platforms

LCD / LED Backlighting

LED Drivers Boost Converters Schottky Diodes

System Voltage Conversion

Low Dropout Regulators DC-DC Converters Schottky Diodes Low-Saturation BJT

Battery Power Management

Current Monitors Load Switches Low-Saturation BJT ZXMP series MOSFETs

Open / Close Detection

Hall Effect Sensors Hall Effect Drivers Audio Amplifier

Buck DC-DC Converters Schottky Diodes Super Barrier Rectifiers

Wireless Connectivity

DC-DC Converters Low Dropout Regulators

System Power Management

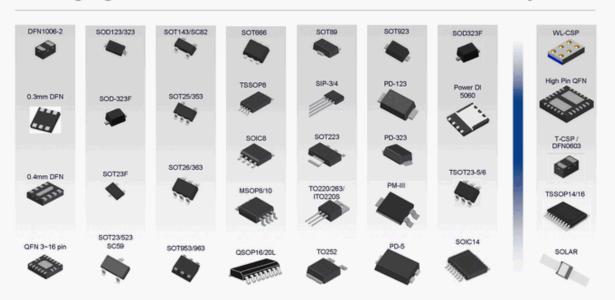
Buck DC-DC Converters Low Dropout Regulators Super Barrier Rectifiers Schottky Diodes P-Channel MOSFETs Low-Saturation BJT

System Interface

USB Power Switches Zener and TVS Arrays



Packaging Focus: Miniaturization and Power Efficiency





Packaging Focus: Miniaturization and Power Efficiency



Efficient Manufacturing + Superior Processes

Packaging

- Shanghai-based packaging with capacity greater than 23 billion units
- Flexible and optimized manufacturing process = low packaging cost
- Additional packaging facilities in Neuhaus, Germany and JV in Chengdu, China

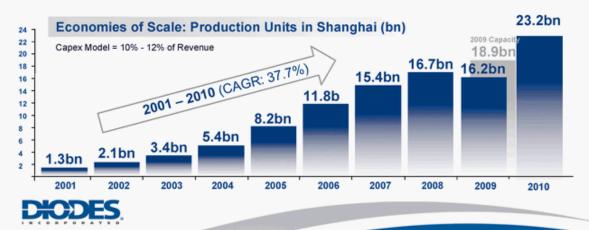


Wafer Fabs

- Bipolar process technology for discrete and ICs
- High volume 5" and 6" wafer fab in Kansas City, Missouri for discretes
- · 6" Wafer fab in Oldham, United Kingdom
- Strong engineering capabilities



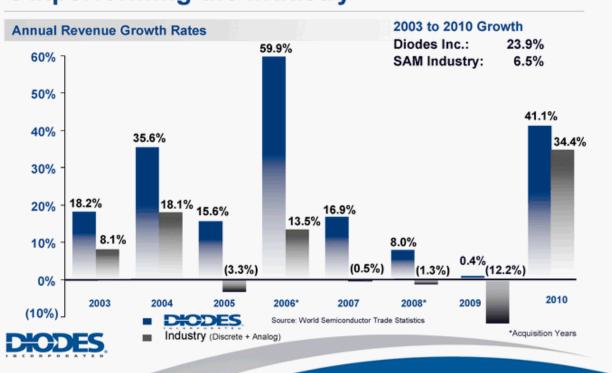


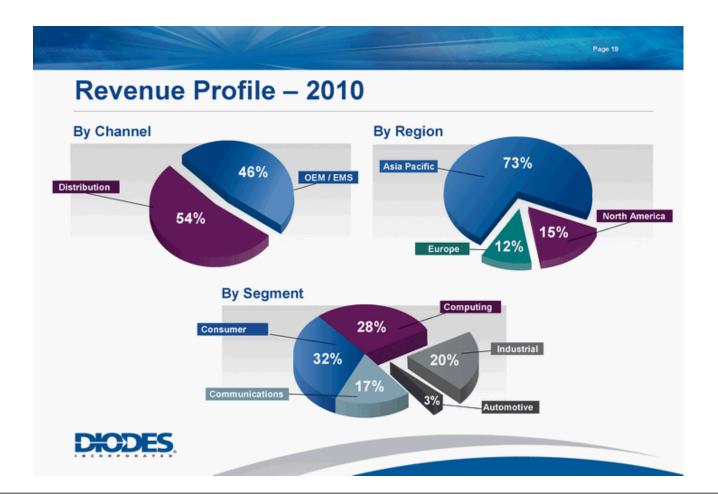


Collaborative Customer Relationships



Outperforming the Industry





Year 2010 Highlights

- Revenue increased to a record \$612.9 million, an increase of 41.1 percent over the \$434.4 million in 2009.
- Gross profit increased \$103.7 million to a record \$224.9 million, an increase of 85.6 percent compared to 2009.
- Gross margin increased 880 basis point to 36.7 percent.
- GAAP net income was a record \$76.7 million, or \$1.68 per diluted share, up from 2009 GAAP net income of \$7.5 million, or \$0.17 per diluted share.
- Non-GAAP adjusted net income was a record \$82.9, or \$1.82 per diluted share, up from 2009 adjusted net income of \$24.1 million, or \$0.55 per diluted share.
- Achieved \$110.8 million cash flow from operations, \$28.9 million net cash flow and \$29.2 million free cash flow.



Fourth Quarter 2010 Financial Performance

(In millions except per share)	4Q09	3Q10	4Q10	Y/Y	Q/Q
Revenue	\$130.3	\$163.1	\$163.8	\$33.5	\$0.7
Revenue Growth	7%	9%	0.4%	25.7%	0.4%
Gross Profit	\$41.8	\$61.0	\$62.6	\$20.8	\$1.6
Gross Margin %	32.1%	37.4%	38.3%	620 bp	90 bp
Operating Profit	\$14	\$30	\$32	\$18	\$2
Net Income	\$14.2	\$21.2	\$24.0	\$9.8	\$2.8
Earning per Share	\$0.32	\$0.46	\$0.52	\$0.20	\$0.06
Cash Flow from Operations	\$22	\$43	\$28	\$6	(\$15)
EBITDA(Non-GAAP)	\$25.3	\$42.3	\$46.3	\$21.0	\$4.0



Balance Sheet

In millions	Dec 31, 2008 (adjusted)	Dec 31, 2009	Dec 31, 2010
Cash	\$104	\$242	\$271
Short-term Investment	\$ -	\$297	\$ -
Inventory	\$ 99	\$ 90	\$121
Current Assets	\$297	\$751	\$541
Long-term Investment	\$321	\$ -	\$ -
Total Assets	\$891	\$1,022	\$847
Convertible Notes ST/LT	\$155	\$121	\$128
Other Long-term Debt	\$217	\$ 3	\$ 3
Total Liabilities	\$491	\$571	\$294
Total Equity	\$400	\$451	\$553



1Q 2011 Business Outlook

- Revenue is expected to be flat to down five percentage points compared to fourth quarter 2010.
- Gross margin is expected to be 36.5 percent, plus or minus one percentage point.
- Operating expenses are anticipated to be comparable to fourth quarter levels on a percent of revenue basis.
- Income tax rate is expected to range between 17 and 23 percent.
- Shares used to calculate GAAP EPS for the first quarter are anticipated to be approximately 46.3 million.



Strategy: Profitable Growth





Thank you

Company Contact:
Diodes Incorporated
Laura Mehrl
Director of Investor Relations
P: 972-385-4492
E: laura_mehrl@diodes.com

Investor Relations Contact: Shelton Group Leanne K. Sievers EVP, Investor Relations P. 949-224-3874 E: Isievers@diodes.com

www.diodes.com